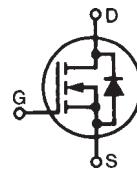


**PolarHV™ HiPerFET  
Power MOSFET  
ISOPLUS247™  
(Electrically Isolated Back Surface)**

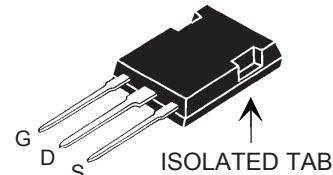
N-Channel Enhancement Mode  
Avalanche Rated  
Fast Intrinsic Diode

**IXFR 48N60P**

$V_{DSS}$	=	600	V
$I_{D25}$	=	32	A
$R_{DS(on)}$	$\leq$	150	$m\Omega$
$t_{rr}$	$\leq$	200	ns



**ISOPLUS247 (IXFR)  
E153432**



G = Gate      D = Drain  
S = Source

Symbol	Test Conditions	Maximum Ratings		
$V_{DSS}$	$T_J = 25^\circ C$ to $150^\circ C$	600	V	
$V_{DGR}$	$T_J = 25^\circ C$ to $150^\circ C$ ; $R_{GS} = 1 M\Omega$	600	V	
$V_{GSS}$	Continuous	$\pm 30$	V	
$V_{GSM}$	Transient	$\pm 40$	V	
$I_{D25}$	$T_c = 25^\circ C$	32	A	
$I_{DM}$	$T_c = 25^\circ C$ , pulse width limited by $T_{JM}$	110	A	
$I_{AR}$	$T_c = 25^\circ C$	32	A	
$E_{AR}$	$T_c = 25^\circ C$	70	mJ	
$E_{AS}$	$T_c = 25^\circ C$	2.0	J	
$dv/dt$	$I_s \leq I_{DM}$ , $dv/dt \leq 100 A/\mu s$ , $V_{DD} \leq V_{DSS}$ , $T_J \leq 150^\circ C$ , $R_G = 4 \Omega$	20	V/ns	
$P_D$	$T_c = 25^\circ C$	300	W	
$T_J$		-55 ... +150	$^\circ C$	
$T_{JM}$		150	$^\circ C$	
$T_{stg}$		-55 ... +150	$^\circ C$	
$T_L$	1.6 mm (0.062 in.) from case for 10 s	300	$^\circ C$	
$V_{ISOL}$	50/60 Hz, RMS, 1 minute	2500	V $\sim$	
$F_c$	Mounting Force	20..120 / 4.5..26	N/lb.	
<b>Weight</b>		5	g	

Symbol	Test Conditions	Characteristic Values		
		Min.	Typ.	Max.
( $T_j = 25^\circ C$ , unless otherwise specified)				
$BV_{DSS}$	$V_{GS} = 0 V$ , $I_D = 250 \mu A$	600		V
$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 8 mA$	3.0		V
$I_{GSS}$	$V_{GS} = \pm 30 V_{DC}$ , $V_{DS} = 0$		$\pm 200$	nA
$I_{DSS}$	$V_{DS} = V_{DSS}$ $V_{GS} = 0 V$		25 1000	$\mu A$
		$T_j = 125^\circ C$		
$R_{DS(on)}$	$V_{GS} = 10 V$ , $I_D = I_T$		150	$m\Omega$

### Features

- International standard isolated package
- UL recognized package
- Silicon chip on Direct-Copper-Bond substrate
  - High power dissipation
  - Isolated mounting surface
  - 2500V electrical isolation
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
  - easy to drive and to protect
- Fast intrinsic diode

### Advantages

- Easy to mount
- Space savings
- High power density

**Symbol****Test Conditions****Characteristic Values** $(T_J = 25^\circ C, \text{ unless otherwise specified})$ **Min.**    **Typ.**    **Max.**

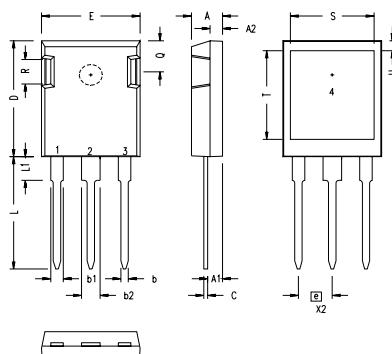
$g_{fs}$	$V_{DS} = 20 V; I_D = I_T, \text{ Notes 1, 2}$	35	53	S
$C_{iss}$ $C_{oss}$ $C_{rss}$	$V_{GS} = 0 V, V_{DS} = 25 V, f = 1 \text{ MHz}$	8860	pF	
		850	pF	
		60	pF	
$t_{d(on)}$ $t_r$ $t_{d(off)}$ $t_f$	$V_{DS} = 0.5 V_{DSS}, I_D = I_T, V_{GS} = 10 V$ $R_G = 2 \Omega \text{ (External)}$	30	ns	
		25	ns	
		85	ns	
		22	ns	
$Q_{g(on)}$ $Q_{gs}$ $Q_{gd}$	$V_{GS} = 10 V, V_{DS} = 0.5 V_{DSS}, I_D = I_T$	150	nC	
		50	nC	
		50	nC	
$R_{thjc}$			0.42	$^\circ \text{C}/\text{W}$
$R_{thcs}$		0.15		$^\circ \text{C}/\text{W}$

**Source-Drain Diode****Characteristic Values** $(T_J = 25^\circ C, \text{ unless otherwise specified})$ **Symbol****Test Conditions****Min.**    **Typ.**    **Max.**

$I_s$	$V_{GS} = 0 V$		32	A
$I_{SM}$	Repetitive		110	A
$V_{SD}$	$I_F = I_S, V_{GS} = 0 V, \text{ Note 1}$		1.5	V
$t_{rr}$ $Q_{RM}$	$I_F = 20 A, -di/dt = 100 A/\mu s$ $V_R = 480 V$		200	ns
			0.8	$\mu C$
$I_{RM}$			6.0	A

## Notes:

1. Pulse test,  $t \leq 300 \mu s$ , duty cycle  $d \leq 2 \%$ ;
2. Test current  $I_T = 24 A$ .

**ISOPLUS247 Outline**

SYM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	.190	.205	4.83	5.21
A1	.090	.100	2.29	2.54
A2	.075	.085	1.91	2.16
b	.045	.055	1.14	1.40
b1	.075	.084	1.91	2.13
b2	.115	.123	2.92	3.12
C	.024	.031	0.61	0.80
D	.819	.840	20.80	21.34
E	.620	.635	15.75	16.13
e	.215	BSC	5.45	BSC
L	.780	.800	19.81	20.32
L1	.150	.170	3.81	4.32
Q	.220	.244	5.59	6.20
R	.170	.190	4.32	4.83
S	.520	.540	13.21	13.72
T	.620	.640	15.75	16.26
U	.065	.080	1.65	2.03

1 - GATE

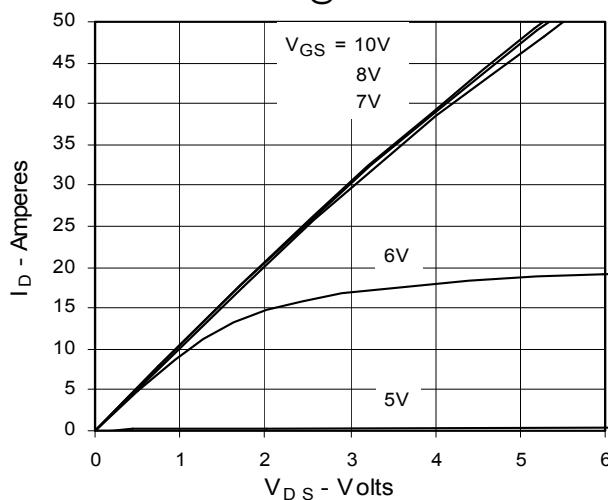
2 - DRAIN (COLLECTOR)

3 - SOURCE (EMITTER)

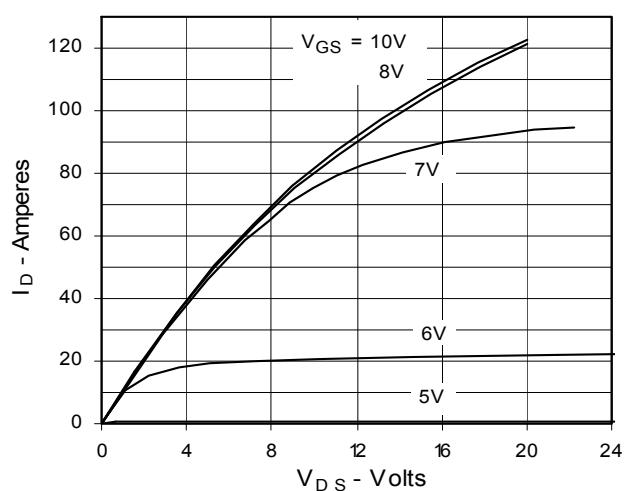
4 - NO CONNECTION

NOTE: This drawing will meet all dimensions requirement of JEDEC outline TO-247AD except screw hole.

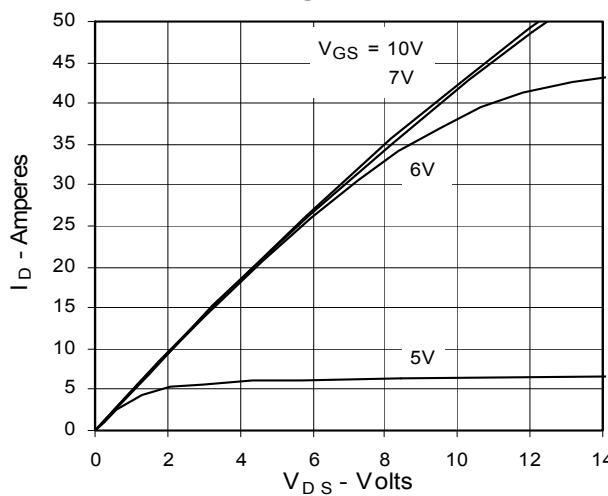
**Fig. 1. Output Characteristics  
@ 25°C**



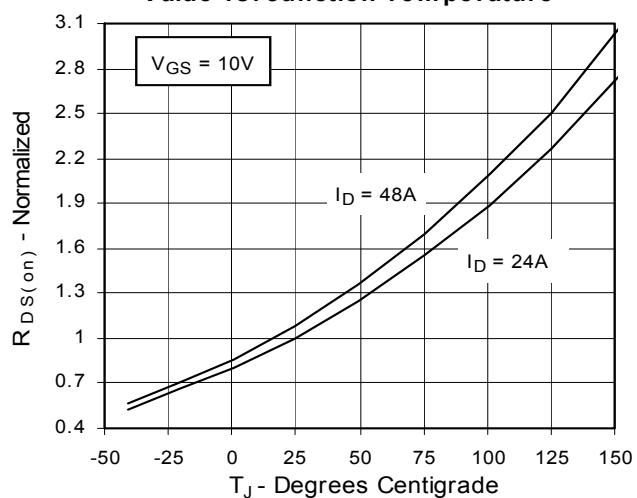
**Fig. 2. Extended Output Characteristics  
@ 25°C**



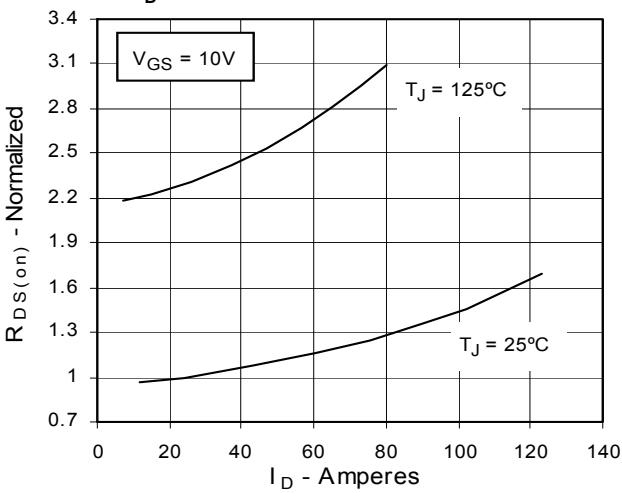
**Fig. 3. Output Characteristics  
@ 125°C**



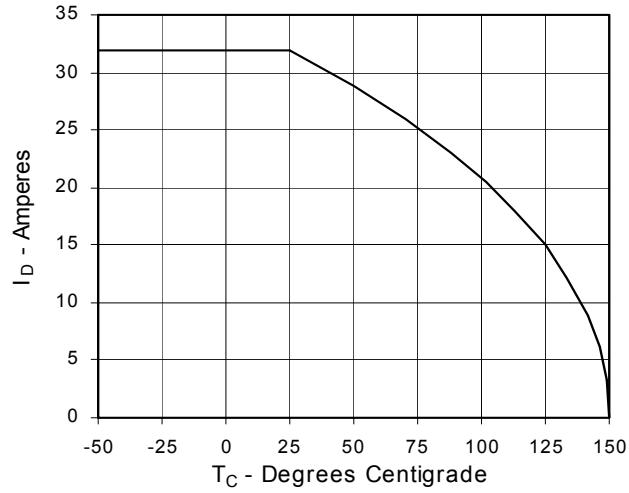
**Fig. 4.  $R_{DS(on)}$  Normalized to  $I_D = 24A$   
Value vs. Junction Temperature**

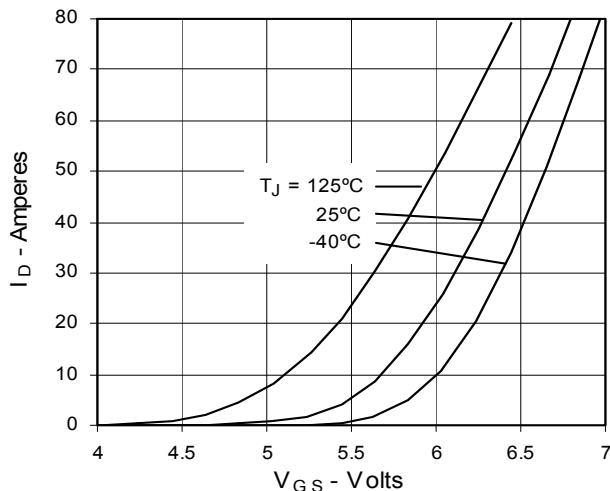
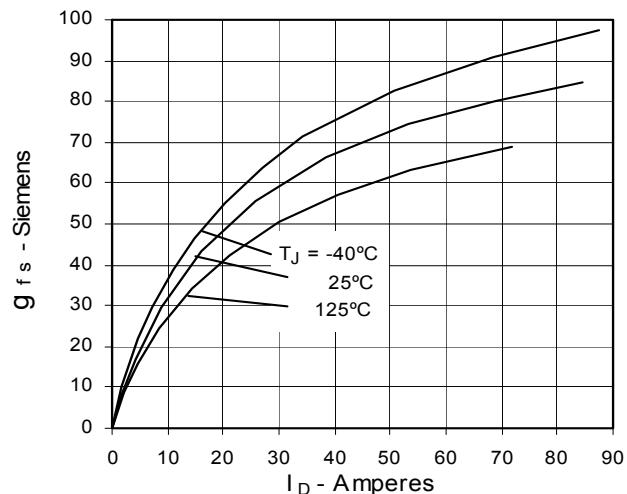
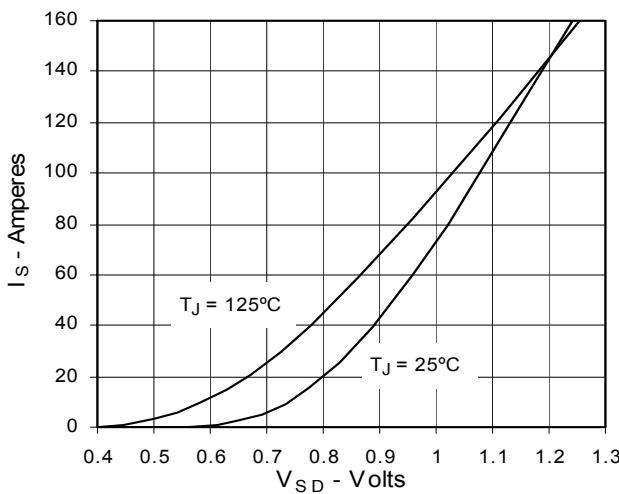
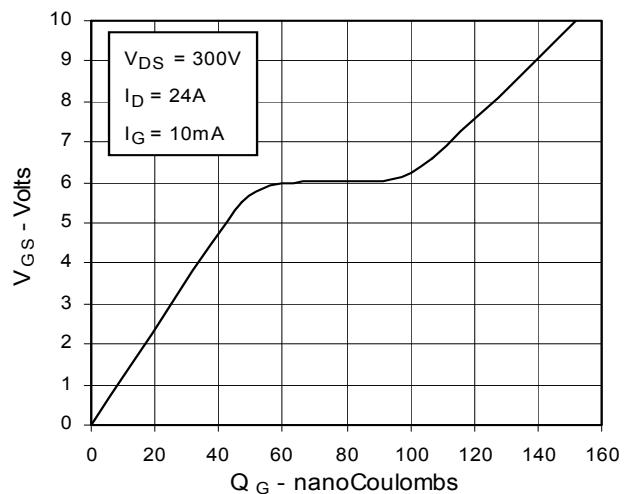
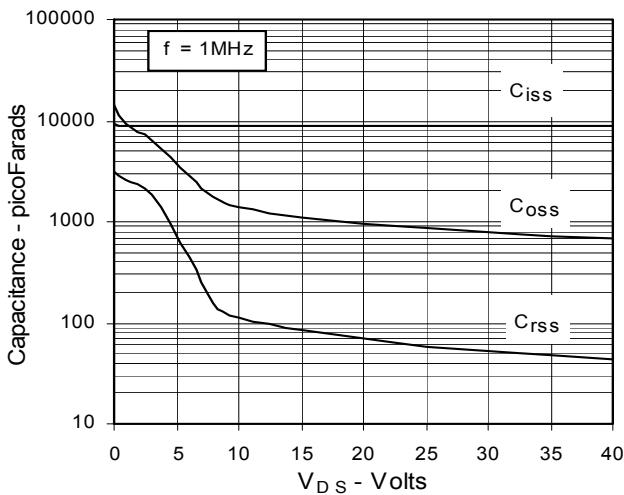
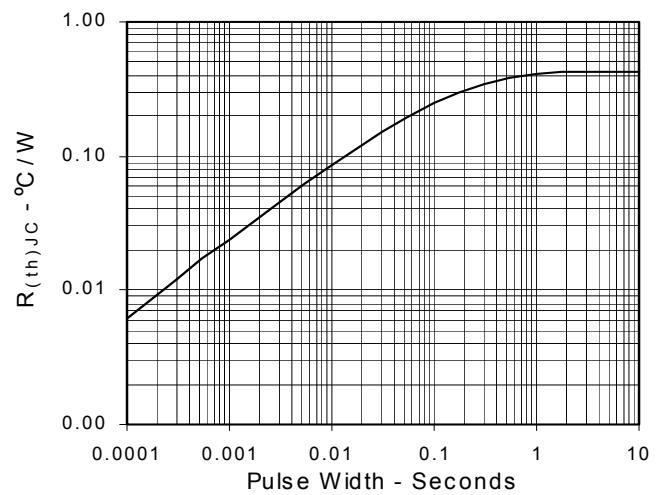


**Fig. 5.  $R_{DS(on)}$  Normalized to  
 $I_D = 24A$  Value vs. Drain Current**



**Fig. 6. Drain Current vs. Case  
Temperature**



**Fig. 7. Input Admittance****Fig. 8. Transconductance****Fig. 9. Source Current vs. Source-To-Drain Voltage****Fig. 10. Gate Charge****Fig. 11. Capacitance****Fig. 13. Maximum Transient Thermal Resistance**



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